NSN 5961-01-167-7431

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-167-7431 **Inclosure Material:** Plastic **Overall Length:** 0.640 inches **Overall Height:** Between 0.225 inches and 0.360 inches **Overall Width:** Between 0.275 inches and 0.310 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 60.0 drain to gate voltage all transistor and 60.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 1.00 amperes drain current all transistor and 100.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 2.0 watts total power dissipation all transistor **Terminal Type And Quantity:** 14 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0